

## Features

- Gain: 16 dB
- Flatness:  $\pm 2$  dB
- 50  $\Omega$  match in and out
- P1dB: +18 dBm @ 14 GHz
- Single DC supply, +5 V to +12 V, 45 mA
- Lead-Free 1.5 x 1.2 mm 6-Lead TDFN package
- Halogen-Free “Green” Mold Compound
- RoHS\* Compliant and 260°C Reflow Compatible

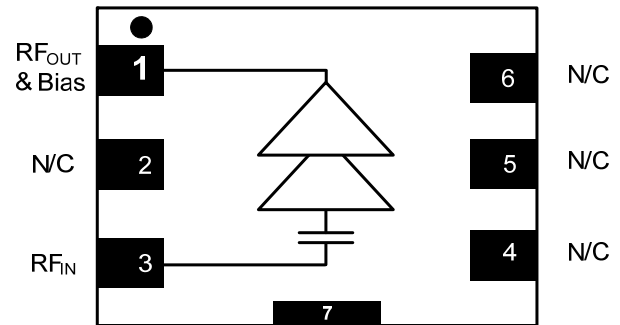
## Description

The MAAM-011101 operates from 4 to 20 GHz and features 16 dB typical gain and +18 dBm of output power. The input and output are fully matched to 50  $\Omega$  with a typical return loss better than 12 dB. Small signal linearity is typically +30 dBm and reverse isolation better than 28 dB. This device requires a minimum of +5V, typically +8V, and maximum +10V for standard operation. Typical current is 45 mA.

Typical usage is a system buffer amplifier, gain block, mixer LO driver, power amplifier driver requiring small size and high performance. Typical applications are for WiFi, WiMAX, Point-to-Point radios, IMS, EW, and Aerospace and Defense.

The MAAM-011101 is housed in a leadless 1.5 x 1.2 mm package that is small yet can be handled and placed with standard pick and place assembly equipment. It is fabricated using a GaAs process which features full passivation for increased performance and reliability.

## Functional Schematic



## Pin Configuration

Pin No.	Pin Name	Description
1	RF <sub>OUT</sub>	RF Output & Bias (Vd)
2	N/C	No Connection
3	RF <sub>IN</sub>	RF Input
4	N/C	No Connection
5	N/C	No Connection
6	N/C	No Connection
7 <sup>1</sup>	Paddle	GND

1. The exposed pad centered on the package bottom must be connected to RF and DC ground.

## Ordering Information <sup>2,3</sup>

Part Number	Package
MAAM-011101-TR1000	1000 Piece Reel
MAAM-011101-001SMB	Sample Test Board

2. Reference Application Note M513 for reel size information.
3. All sample boards include 5 loose parts.

\* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

**Electrical Specifications:  $T_A = +25^\circ\text{C}$ ,  $V_D = +8$  Volts,  $Z_0 = 50 \Omega$**

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Gain	4 GHz	dB	—	13	—
	8 GHz		17		
	12 GHz		—	16	
	16 GHz		—	15	
	20 GHz		—	15	
Noise Figure	4 - 20 GHz	dB	—	4	—
Input Return Loss	6 - 18 GHz	dB	—	12	—
Output Return Loss	6 - 18 GHz	dB	—	14	—
Isolation	4 - 20 GHz	dB	—	30	—
P1dB	4 GHz	dBm	—	+15	—
	8 GHz		+16	+17	
	12 GHz		—	+19	
	16 GHz		—	+19	
	20 GHz		—	+18	
$I_{DD}$	+8 Volts	mA	35	45	55

**Absolute Maximum Ratings** <sup>4,5,6</sup>

Parameter	Absolute Maximum
RF Input Power	+23 dBm
Voltage	+12 volts
Operating Temperature	-40°C to +85°C
Junction Temperature <sup>7</sup>	+150°C
Storage Temperature	-65°C to +150°C

4. Exceeding any one or combination of these limits may cause permanent damage to this device.
5. M/A-COM Technology Solutions does not recommend sustained operation near these survivability limits.
6. Operating at nominal conditions with  $T_J \leq +150^\circ\text{C}$  will ensure  $MTTF > 1 \times 10^6$  hours.
7. Junction Temperature ( $T_J$ ) =  $T_C + \Theta_{JC} * ((V * I) - (P_{OUT} - P_{IN}))$   
Typical thermal resistance ( $\Theta_{JC}$ ) = 40°C/W
  - a) For  $T_C = 25^\circ\text{C}$ ,  
 $T_J = +43^\circ\text{C}$  @ +10 V, 45 mA,  $P_{OUT} = -4$  dBm,  $P_{IN} = -20$  dBm
  - b) For  $T_C = 85^\circ\text{C}$ ,  
 $T_J = +103^\circ\text{C}$  @ +10 V, 45 mA,  $P_{OUT} = -3$  dBm,  $P_{IN} = -20$  dBm

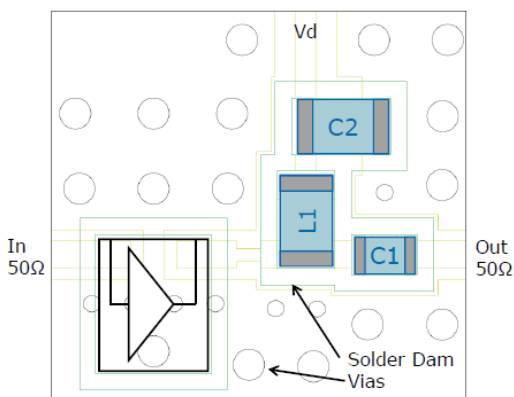
**Handling Procedures**

Please observe the following precautions to avoid damage:

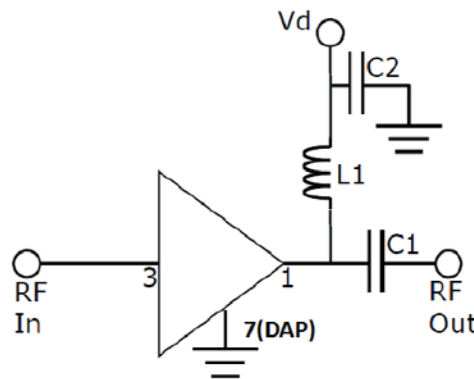
**Static Sensitivity**

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these Class 0 devices.

## Recommended PCB



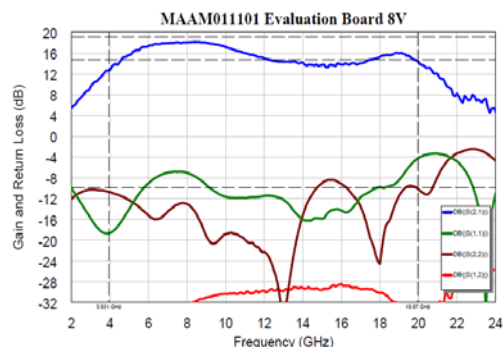
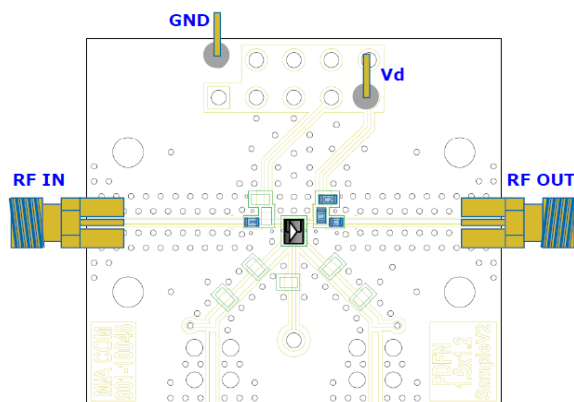
## Application Schematic



## Parts List

Comp.	Value	Pkg.	Manf.	Purpose
C1	100 pF	0201	Murata GRM0335C1E101	DC Block
C2	100 pF	0402	Murata GRM1555C1E101	Bypass
L1	470 Ω	0402	Murata BLM15GG471	Choke

## Evaluation Board



## Application Information

The MAAM-011101 is designed to be easy to use yet high performance. The ultra small size, no matching, and simple bias allows easy placement on any system board.

### LO Buffer applications:

The MAAM-011101 is good as a LO buffer since it has excellent isolation, selectable power output, low phase noise, and 50 Ω match (even under heavy drive). It is designed to deliver saturated output levels up to +20 dBm common to driving mixer configurations. It is typically used in conjunction with filters or splitters after the VCO or PLL.

### PA Driver applications:

The MAAM-011101 makes a very good low cost driver before the transmit power amplifier. Set typically 7 dB backed off P1dB as a linear driver, it still delivers up to +12 dBm. Often cascaded in series with an attenuator, it allows gain control with little pulling due to mis-match. The low gain expansion allows little AM-to-AM distortion.

### Grounding:

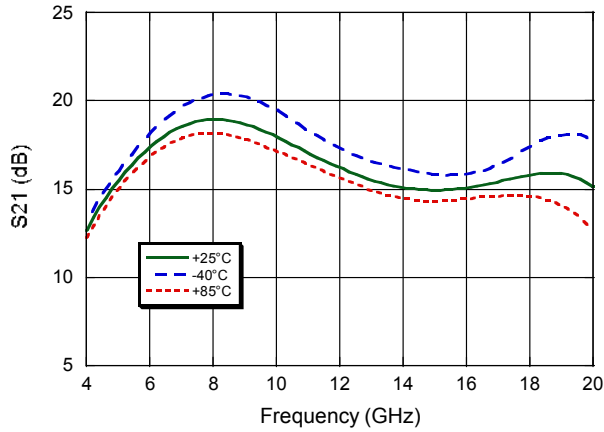
It is recommended that the total ground (common mode) inductance not exceed 0.03 nH (30 pH). This is equivalent to at least four 8 mil (200 u) vias per 8 mil board (200 u) be place under the device to ground

### DC Bias Tee:

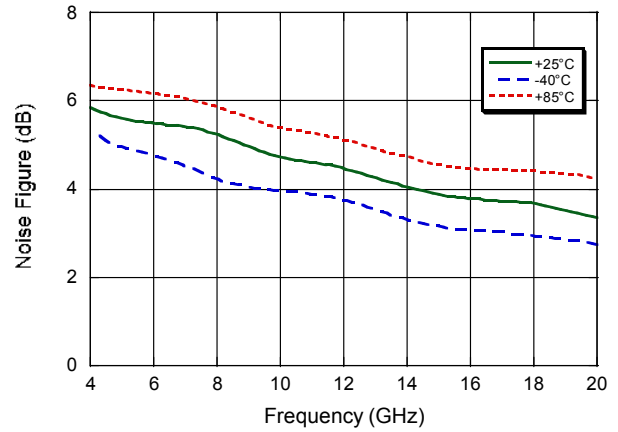
To bias properly, a DC voltage must be applied at the output pin. Typically this is down with a 2 element bias network that consists of a choke and a DC blocking capacitor. We recommend a high Q inductor for the choke and quality capacitor for the DC block.

**Typical Performance Curves over temperature,  $V_D = +8\text{ V}$ ,  $Z_0 = 50\ \Omega$**

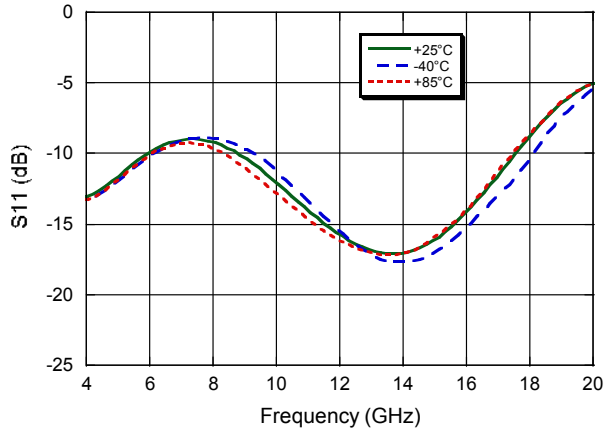
**Gain**



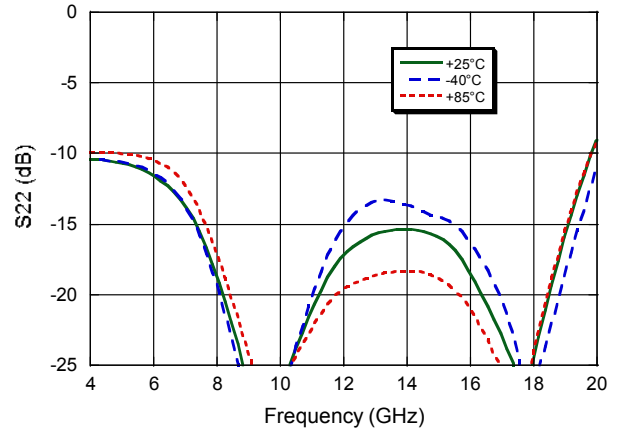
**Noise Figure**



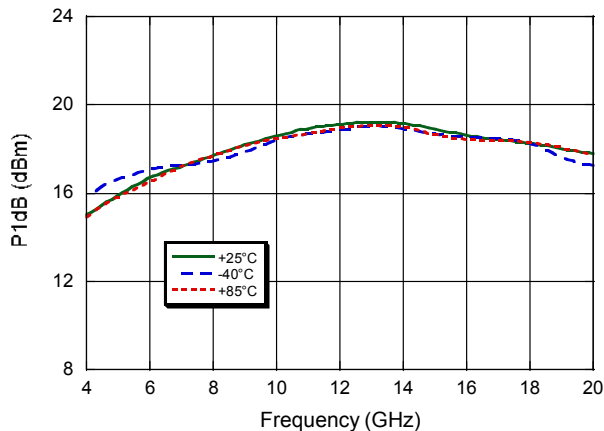
**Input Return Loss**



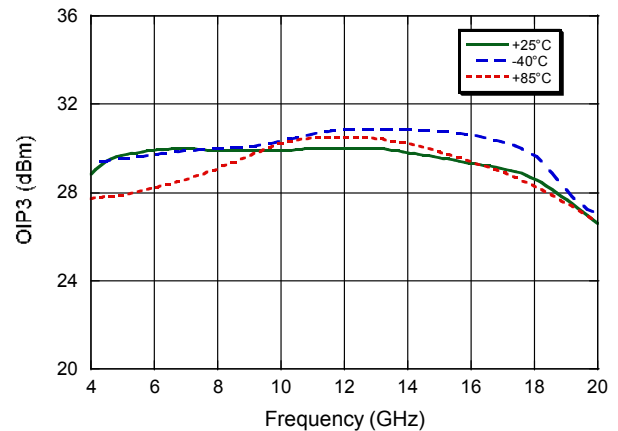
**Output Return Loss**



**Output P1dB**

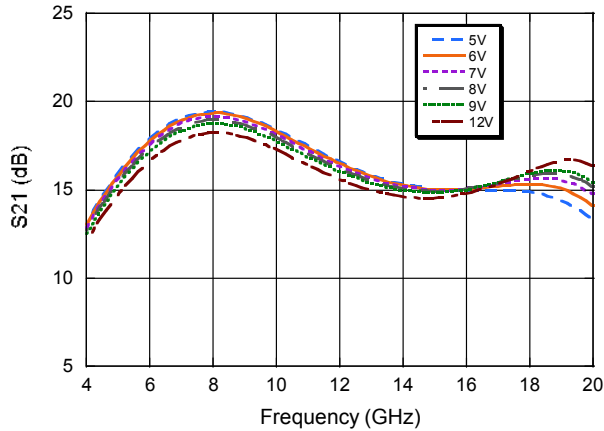


**Output IP3**

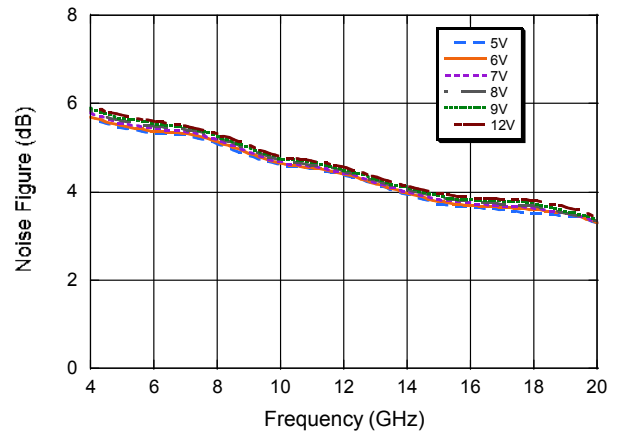


**Typical Performance Curves over supply voltage,  $T_A = +25^\circ\text{C}$ ,  $Z_0 = 50 \Omega$**

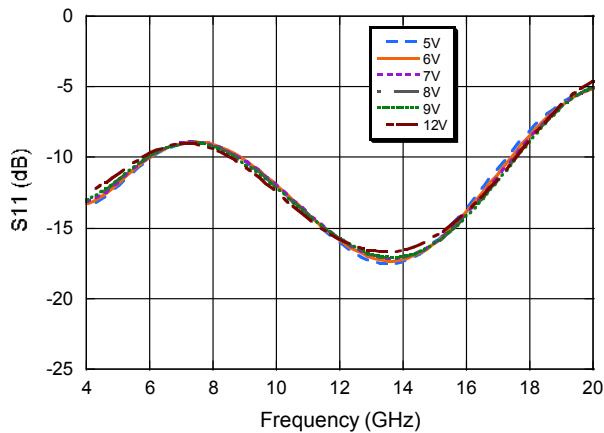
**Gain**



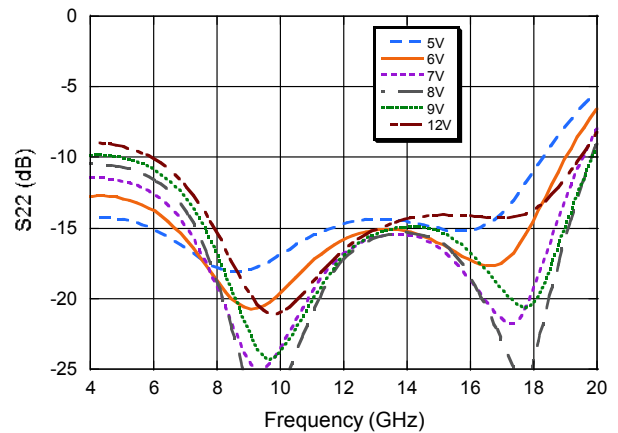
**Noise Figure**



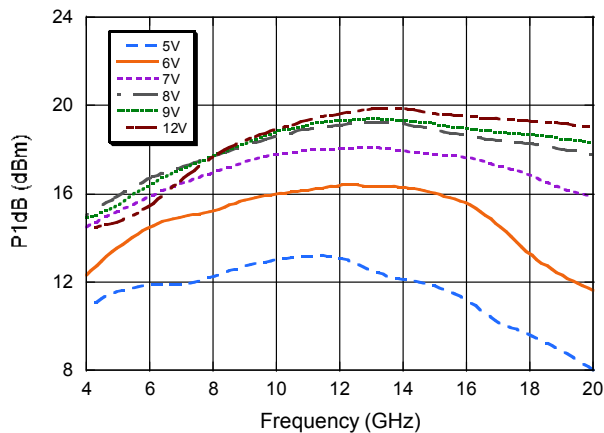
**Input Return Loss**



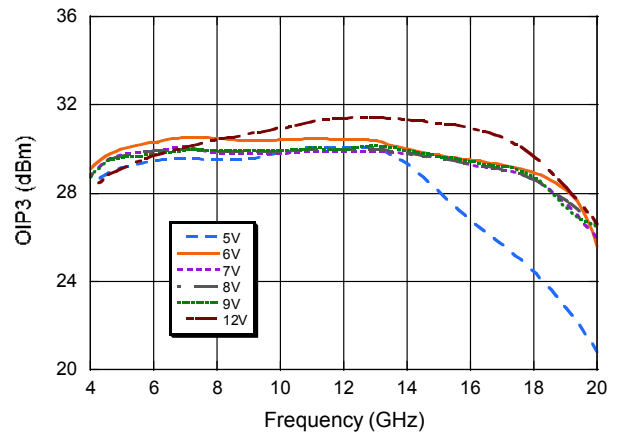
**Output Return Loss**



**Output P1dB**

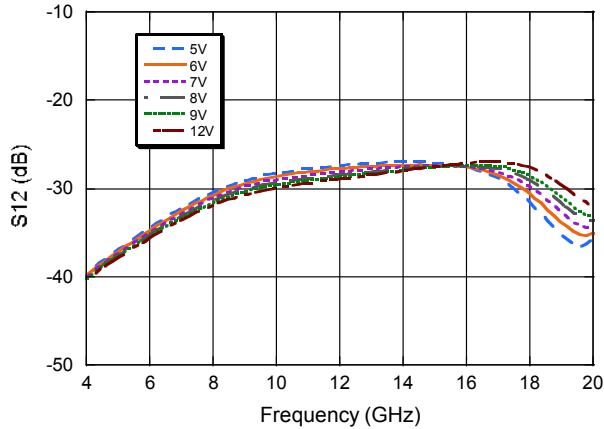


**Output IP3**

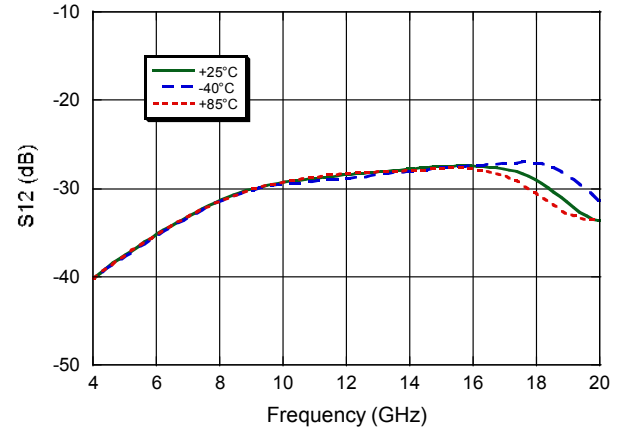


## Typical Performance Curves

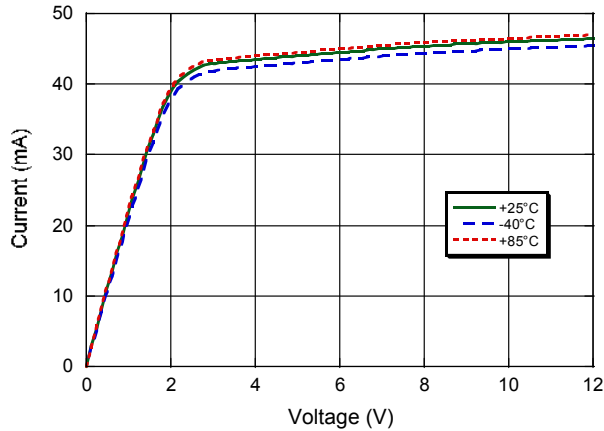
**Isolation over voltage**



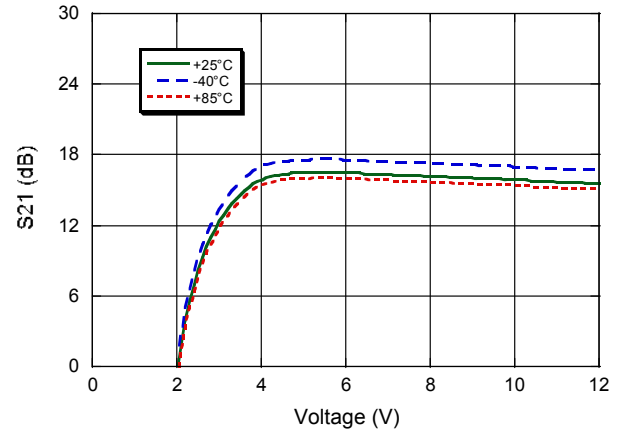
**Isolation over temperature**



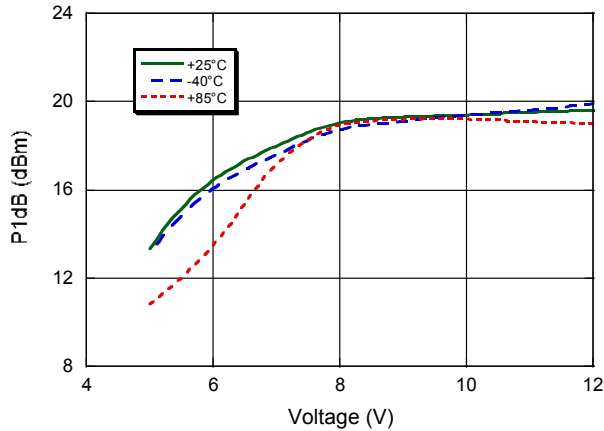
**Current vs. Voltage over temperature**



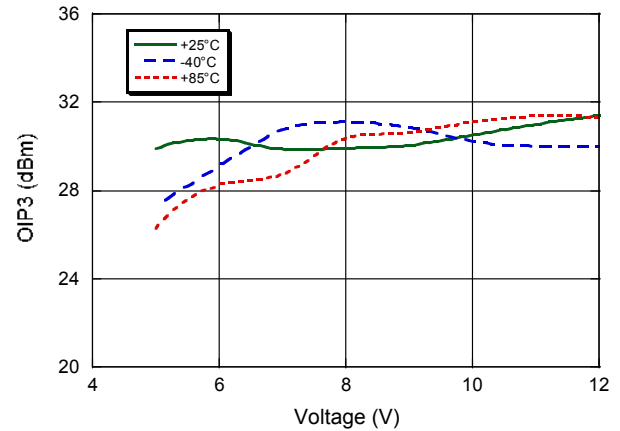
**Gain vs. Voltage over temperature @ 12 GHz**



**Output P1dB @ 12 GHz**



**Output IP3 @ 12 GHz**







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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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